

## LMH2110 8 GHz Logarithmic RMS Power Detector with 45 dB dynamic range

Check for Samples: [LMH2110](#)

### FEATURES

- **Logarithmic Root Mean Square Response**
- **45 dB Linear-in-dB Power Detection Range**
- **Multi-Band Operation from 50 MHz to 8 GHz**
- **LOG Conformance Better than  $\pm 0.5$  dB**
- **Highly Temperature Insensitive,  $\pm 0.25$  dB**
- **Modulation Independent Response, 0.08 dB**
- **Minimal Slope and Intercept Variation**
- **Shutdown Functionality**
- **Wide Supply Range from 2.7V to 5V**
- **Tiny 6-Bump DSBGA Package**

### APPLICATIONS

- **Multi Mode, Multi Band RF Power Control**
  - GSM/EDGE
  - CDMA/CDMA2000
  - W-CDMA
  - OFDMA
  - LTE
- **Infrastructure RF Power Control**

### DESCRIPTION

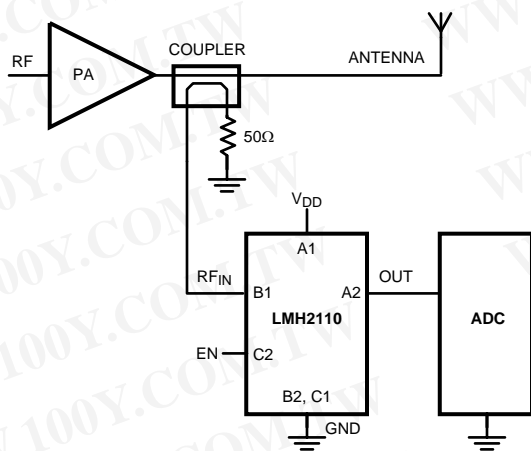
The LMH2110 is a 45 dB Logarithmic RMS power detector particularly suited for accurate power measurement of modulated RF signals that exhibit large peak-to-average ratios, i.e. large variations of the signal envelope. Such signals are encountered in W-CDMA and LTE cell phones. The RMS measurement topology inherently ensures a modulation insensitive measurement.

The device has an RF frequency range from 50 MHz to 8 GHz. It provides an accurate, temperature and supply insensitive, output voltage that relates linearly to the RF input power in dBm. The LMH2110's excellent conformance to a logarithmic response enables an easy integration by using slope and intercept only, reducing calibration effort significantly. The device operates with a single supply from 2.7V to 5V. The LMH2110 has an RF power detection range from -40 dBm to 5 dBm and is ideally suited for use in combination with a directional coupler. Alternatively a resistive divider can be used as well.

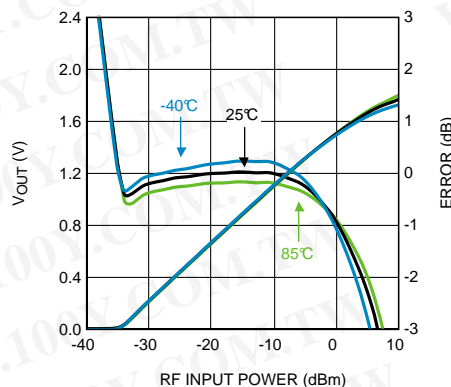
The device is active for EN = High, otherwise it is in a low power consumption shutdown mode. To save power and prevent discharge of an external filter capacitance, the output (OUT) is high-impedance during shutdown.

The LMH2110 power detector is offered in a tiny 6-bump DSBGA package.

### Typical Application Circuit



**Output Voltage and Log Conformance Error vs. RF Input Power at 1900 MHz**



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### Absolute Maximum Ratings <sup>(1)(2)</sup>

Supply Voltage	
V <sub>BAT</sub> - GND	5.5V
RF Input	
Input power	12 dBm
DC Voltage	1V
Enable Input Voltage	GND-0.4V < V <sub>EN</sub> and V <sub>EN</sub> < Min (V <sub>DD</sub> -0.4, 3.6V)
ESD Tolerance <sup>(3)</sup>	
Human Body Model	2000V
Machine Model	200V
Charge Device Model	1000V
Storage Temperature Range	-65°C to 150°C
Junction Temperature <sup>(4)</sup>	150°C
Maximum Lead Temperature	
(Soldering, 10 sec)	260°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) Human body model, applicable std. MIL-STD-883, Method 3015.7. Machine model, applicable std. JESD22-A115-A (ESD MM std of JEDEC). Field-Induced Charge-Device Model, applicable std. JESD22-C101-C. (ESD FICDM std. of JEDEC)
- (4) The maximum power dissipation is a function of T<sub>J(MAX)</sub>, θ<sub>JA</sub>. The maximum allowable power dissipation at any ambient temperature is P<sub>D</sub> = (T<sub>J(MAX)</sub> - T<sub>A</sub>)/θ<sub>JA</sub>. All numbers apply for packages soldered directly into a PC board.

### Operating Ratings <sup>(1)</sup>

Supply Voltage	2.7V to 5V
Temperature Range	-40°C to +85°C
RF Frequency Range	50 MHz to 8 GHz
RF Input Power Range	-40 dBm to 5 dBm
Package Thermal Resistance θ <sub>JA</sub> <sup>(2)</sup>	166.7°C/W

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- (2) The maximum power dissipation is a function of T<sub>J(MAX)</sub>, θ<sub>JA</sub>. The maximum allowable power dissipation at any ambient temperature is P<sub>D</sub> = (T<sub>J(MAX)</sub> - T<sub>A</sub>)/θ<sub>JA</sub>. All numbers apply for packages soldered directly into a PC board.

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## 2.7V and 4.5V DC and AC Electrical Characteristics

Unless otherwise specified: all limits are ensured to;  $T_A = 25^\circ\text{C}$ ,  $V_{\text{BAT}} = 2.7\text{V}$  and  $4.5\text{V}$  (worst of the 2 is specified),  $\text{RF}_{\text{IN}} = 1900\text{ MHz CW}$  (Continuous Wave, unmodulated). **Boldface** limits apply at the temperature extremes <sup>(1)</sup>.

Symbol	Parameter	Condition	Min (2)	Typ (3)	Max (2)	Units	
<b>Supply Interface</b>							
$I_{\text{BAT}}$	Supply Current	Active mode: EN = High, no signal present at $\text{RF}_{\text{IN}}$ .	3.7 <b>2.9</b>	4.8	5.5 <b>5.9</b>	mA	
		Shutdown: EN = Low, no signal present at $\text{RF}_{\text{IN}}$ .	$V_{\text{BAT}} = 2.7\text{V}$		3.7	4.7 <b>5</b>	$\mu\text{A}$
			$V_{\text{BAT}} = 4.5\text{V}$		4.6	5.7 <b>6.1</b>	
		EN = Low, $\text{RF}_{\text{IN}} = 0\text{ dBm}$ , 1900 MHz	$V_{\text{BAT}} = 2.7\text{V}$		3.5	4.7 <b>5</b>	$\mu\text{A}$
$V_{\text{BAT}} = 4.5\text{V}$			4.6	5.7 <b>6.1</b>			
PSRR	Power Supply Rejection Ratio (4)	$\text{RF}_{\text{IN}} = -10\text{ dBm}$ , 1900 MHz, $2.7\text{V} < V_{\text{BAT}} < 5\text{V}$	<b>45</b>	56		dB	
<b>Logic Enable Interface</b>							
$V_{\text{LOW}}$	EN Logic Low Input Level (Shutdown mode)				<b>0.6</b>	V	
$V_{\text{HIGH}}$	EN Logic High Input Level		<b>1.1</b>			V	
$I_{\text{EN}}$	Current into EN Pin				<b>50</b>	nA	
<b>Input / Output Interface</b>							
$R_{\text{IN}}$	Input Resistance		44	50	56	$\Omega$	
$V_{\text{OUT}}$	Minimum Output Voltage (Pedestal)	No input Signal	<b>0</b>	1.5	<b>8</b>	mV	
$R_{\text{OUT}}$	Output Impedance	EN = High, $\text{RF}_{\text{IN}} = -10\text{ dBm}$ , 1900 MHz, $I_{\text{LOAD}} = 1\text{ mA}$ , DC measurement		0.2	<b>2</b> <b>3</b>	$\Omega$	
$I_{\text{OUT}}$	Output Short Circuit Current	Sinking, $\text{RF}_{\text{IN}} = -10\text{ dBm}$ , OUT connected to 2.5V	37 <b>32</b>	42		mA	
		Sourcing, $\text{RF}_{\text{IN}} = -10\text{ dBm}$ , OUT connected to GND	40 <b>34</b>	46			
$I_{\text{OUT,SD}}$	Output Leakage Current in Shutdown mode	EN = Low, OUT connected to 2V			<b>50</b>	nA	
$e_n$	Output Referred Noise (4)	$\text{RF}_{\text{IN}} = -10\text{ dBm}$ , 1900 MHz, output spectrum at 10 kHz		3		$\mu\text{V}/\sqrt{\text{Hz}}$	
$v_n$	Integrated Output Referred Noise (4)	Integrated over frequency band 1 kHz - 6.5 kHz, $\text{RF}_{\text{IN}} = -10\text{ dBm}$ , 1900 MHz		210		$\mu\text{V}_{\text{RMS}}$	
<b>Timing Characteristics</b>							
$t_{\text{ON}}$	Turn-on Time from shutdown	$\text{RF}_{\text{IN}} = -10\text{ dBm}$ , 1900 MHz, EN Low-High transition to OUT at 90%		15	19	$\mu\text{s}$	
$t_{\text{R}}$	Rise Time (4)	Signal at $\text{RF}_{\text{IN}}$ from -20 dBm to 0 dBm, 10% to 90%, 1900 MHz		2.2		$\mu\text{s}$	
$t_{\text{F}}$	Fall Time (4)	Signal at $\text{RF}_{\text{IN}}$ from 0 dBm to -20 dBm, 90% to 10%, 1900 MHz		31		$\mu\text{s}$	

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that  $T_J = T_A$ . No assurance of parametric performance is indicated in the electrical tables under conditions of internal self-heating where  $T_J > T_A$ .
- (2) All limits are specified by test or statistical analysis.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not specified on shipped production material.
- (4) This parameter is specified by design and/or characterization and is not tested in production.

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## 2.7V and 4.5V DC and AC Electrical Characteristics (continued)

Unless otherwise specified: all limits are ensured to;  $T_A = 25^\circ\text{C}$ ,  $V_{\text{BAT}} = 2.7\text{V}$  and  $4.5\text{V}$  (worst of the 2 is specified),  $\text{RF}_{\text{IN}} = 1900\text{ MHz CW}$  (Continuous Wave, unmodulated). **Boldface** limits apply at the temperature extremes <sup>(1)</sup>.

Symbol	Parameter	Condition	Min (2)	Typ (3)	Max (2)	Units
<b>RF Detector Transfer</b>						
<b><math>\text{RF}_{\text{IN}} = 50\text{ MHz}</math>, fit range -20 dBm to -10 dBm <sup>(5)</sup></b>						
$P_{\text{MIN}}$	Minimum Power level, bottom end of dynamic range	Log Conformance Error within $\pm 1\text{ dB}$		-39		dBm
$P_{\text{MAX}}$	Maximum Power level, top end of dynamic range			7		
$V_{\text{MIN}}$	Minimum Output Voltage	At $P_{\text{MIN}}$		3		mV
$V_{\text{MAX}}$	Maximum Output Voltage	At $P_{\text{MAX}}$		1.96		V
$K_{\text{SLOPE}}$	Logarithmic Slope		42.2	44.3	46.4	mV/dB
$P_{\text{INT}}$	Logarithmic Intercept		-38.6	-38.3	-38.0	dBm
DR	Dynamic Range for specified accuracy	$\pm 1\text{ dB}$ Log Conformance Error ( $E_{\text{LC}}$ )		46 <b>45</b>		dB
		$\pm 3\text{ dB}$ Log Conformance Error ( $E_{\text{LC}}$ )		51 <b>50</b>		
		$\pm 0.5\text{ dB}$ Input referred Variation over Temperature ( $E_{\text{VOT}}$ ), from $P_{\text{MIN}}$		<b>42</b>		
<b><math>\text{RF}_{\text{IN}} = 900\text{ MHz}</math>, fit range -20 dBm to -10 dBm <sup>(5)</sup></b>						
$P_{\text{MIN}}$	Minimum Power level, bottom end of dynamic range	Log Conformance Error within $\pm 1\text{ dB}$		-38		dBm
$P_{\text{MAX}}$	Maximum Power level, top end of dynamic range			0		
$V_{\text{MIN}}$	Minimum Output Voltage	At $P_{\text{MIN}}$		3		mV
$V_{\text{MAX}}$	Maximum Output Voltage	At $P_{\text{MAX}}$		1.58		V
$K_{\text{SLOPE}}$	Logarithmic Slope		41.8	43.9	46.0	mV/dB
$P_{\text{INT}}$	Logarithmic Intercept		-37.4	-37.0	-36.7	dBm
DR	Dynamic Range for specified accuracy	$\pm 1\text{ dB}$ Log Conformance Error ( $E_{\text{LC}}$ )		38 <b>37</b>		dB
		$\pm 3\text{ dB}$ Log Conformance Error ( $E_{\text{LC}}$ )		45 <b>44</b>		
		$\pm 0.5\text{ dB}$ Input referred Variation over Temperature ( $E_{\text{VOT}}$ ), from $P_{\text{MIN}}$		<b>44</b>		
		$\pm 0.3\text{ dB}$ Error for a 1dB Step ( $E_{1\text{dB STEP}}$ )		41 <b>38</b>		
		$\pm 1\text{ dB}$ Error for a 10dB Step ( $E_{10\text{dB STEP}}$ )		<b>32</b>		
$E_{\text{MOD}}$	Input referred Variation due to Modulation	W-CDMA Release 6/7/8, -38 dBm < $\text{RF}_{\text{IN}} < -5\text{ dBm}$		0.08		dB
		LTE, -38 dBm < $\text{RF}_{\text{IN}} < -5\text{ dBm}$		0.19		
<b><math>\text{RF}_{\text{IN}} = 1900\text{ MHz}</math>, fit range -20 dBm to -10 dBm <sup>(5)</sup></b>						
$P_{\text{MIN}}$	Minimum Power level, bottom end of dynamic range	Log Conformance Error within $\pm 1\text{ dB}$		-36		dBm
$P_{\text{MAX}}$	Maximum Power level, top end of dynamic range			0		
$V_{\text{MIN}}$	Minimum Output Voltage	At $P_{\text{MIN}}$		3		mV
$V_{\text{MAX}}$	Maximum Output Voltage	At $P_{\text{MAX}}$		1.5		V
$K_{\text{SLOPE}}$	Logarithmic Slope		41.8	43.9	46.1	mV/dB
$P_{\text{INT}}$	Logarithmic Intercept		-35.5	-35.1	-34.7	dBm

(5) All limits are specified by design and measurements which are performed on a limited number of samples. Limits represent the mean  $\pm 3$ -sigma values. The typical value represents the statistical mean value.

**2.7V and 4.5V DC and AC Electrical Characteristics (continued)**

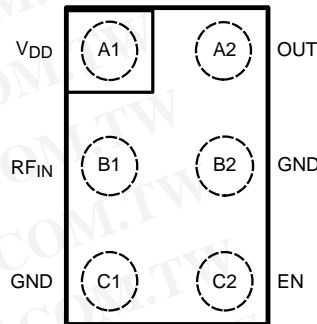
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Symbol	Parameter	Condition	Min (2)	Typ (3)	Max (2)	Units
DR	Dynamic Range for specified accuracy	$\pm 1\text{ dB}$ Log Conformance Error ( $E_{\text{LC}}$ )		36 <b>36</b>		dB
		$\pm 3\text{ dB}$ Log Conformance Error ( $E_{\text{LC}}$ )		45 <b>43</b>		
		$\pm 0.5\text{ dB}$ Input referred Variation over Temperature ( $E_{\text{VOT}}$ ), from $P_{\text{MIN}}$		<b>41</b>		
		$\pm 0.3\text{ dB}$ Error for a 1dB Step ( $E_{1\text{dB STEP}}$ )		40 <b>38</b>		
		$\pm 1\text{ dB}$ Error for a 10dB Step ( $E_{10\text{dB STEP}}$ )		<b>30</b>		
$E_{\text{MOD}}$	Input referred Variation due to Modulation	W-CDMA Release 6/7/8, $-38\text{ dBm} < \text{RF}_{\text{IN}} < -5\text{ dBm}$		0.09		dB
		LTE, $-38\text{ dBm} < \text{RF}_{\text{IN}} < -5\text{ dBm}$		0.18		
<b><math>\text{RF}_{\text{IN}} = 3500\text{ MHz}</math>, fit range <math>-15\text{ dBm}</math> to <math>-5\text{ dBm}</math> <sup>(5)</sup></b>						
$P_{\text{MIN}}$	Minimum Power level, bottom end of dynamic range	Log Conformance Error within $\pm 1\text{ dB}$		-31		dBm
$P_{\text{MAX}}$	Maximum Power level, top end of dynamic range			6		
$V_{\text{MIN}}$	Minimum Output Voltage	At $P_{\text{MIN}}$		2		mV
$V_{\text{MAX}}$	Maximum Output Voltage	At $P_{\text{MAX}}$		1.52		V
$K_{\text{SLOPE}}$	Logarithmic Slope		41.8	44.0	46.1	mV/dB
$P_{\text{INT}}$	Logarithmic Intercept		-30.5	-29.7	-28.8	dBm
DR	Dynamic Range for specified accuracy	$\pm 1\text{ dB}$ Log Conformance Error ( $E_{\text{LC}}$ )		37 <b>36</b>		dB
		$\pm 3\text{ dB}$ Log Conformance Error ( $E_{\text{LC}}$ )		44 <b>42</b>		
		$\pm 0.5\text{ dB}$ Input referred Variation over Temperature ( $E_{\text{VOT}}$ ), from $P_{\text{MIN}}$		<b>39</b>		
<b><math>\text{RF}_{\text{IN}} = 5800\text{ MHz}</math>, fit range <math>-20\text{ dBm}</math> to <math>3\text{ dBm}</math> <sup>(6)</sup></b>						
$P_{\text{MIN}}$	Minimum Power level, bottom end of dynamic range	Log Conformance Error within $\pm 1\text{ dB}$		-22		dBm
$P_{\text{MAX}}$	Maximum Power level, top end of dynamic range			10		
$V_{\text{MIN}}$	Minimum Output Voltage	At $P_{\text{MIN}}$		3		mV
$V_{\text{MAX}}$	Maximum Output Voltage	At $P_{\text{MAX}}$		1.34		V
$K_{\text{SLOPE}}$	Logarithmic Slope		42.5	44.8	47.1	mV/dB
$P_{\text{INT}}$	Logarithmic Intercept		-22.0	-21.0	-19.9	dBm
DR	Dynamic Range for specified accuracy	$\pm 1\text{ dB}$ Log Conformance Error ( $E_{\text{LC}}$ )		32 <b>31</b>		dB
		$\pm 3\text{ dB}$ Log Conformance Error ( $E_{\text{LC}}$ )		39 <b>37</b>		
		$\pm 0.5\text{ dB}$ Input referred Variation over Temperature ( $E_{\text{VOT}}$ ), from $P_{\text{MIN}}$		<b>33</b>		

(6) All limits are specified by design and measurements which are performed on a limited number of samples. Limits represent the mean  $\pm 3$ -sigma values. The typical value represents the statistical mean value.

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### CONNECTION DIAGRAM



**Figure 1. 6-Bump DSBGA  
Top View**

**Table 1. PIN DESCRIPTIONS**

	DSBGA	Name	Description
Power Supply	A1	V <sub>DD</sub>	Positive Supply Voltage.
	C1	GND	Power Ground.
	B2	GND	Power Ground. May be left floating in case grounding is not feasible.
Logic Input	C2	EN	The device is enabled for EN = High, and in shutdown mode for EN = Low. EN should be <2.5V for having low I <sub>EN</sub> . For EN >2.5V, I <sub>EN</sub> increases slightly, while device is still functional. Absolute maximum rating for EN = 3.6V.
Analog Input	B1	RF <sub>IN</sub>	RF input signal to the detector, internally terminated with 50Ω.
Output	A2	OUT	Ground referenced detector output voltage.

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BLOCK DIAGRAM

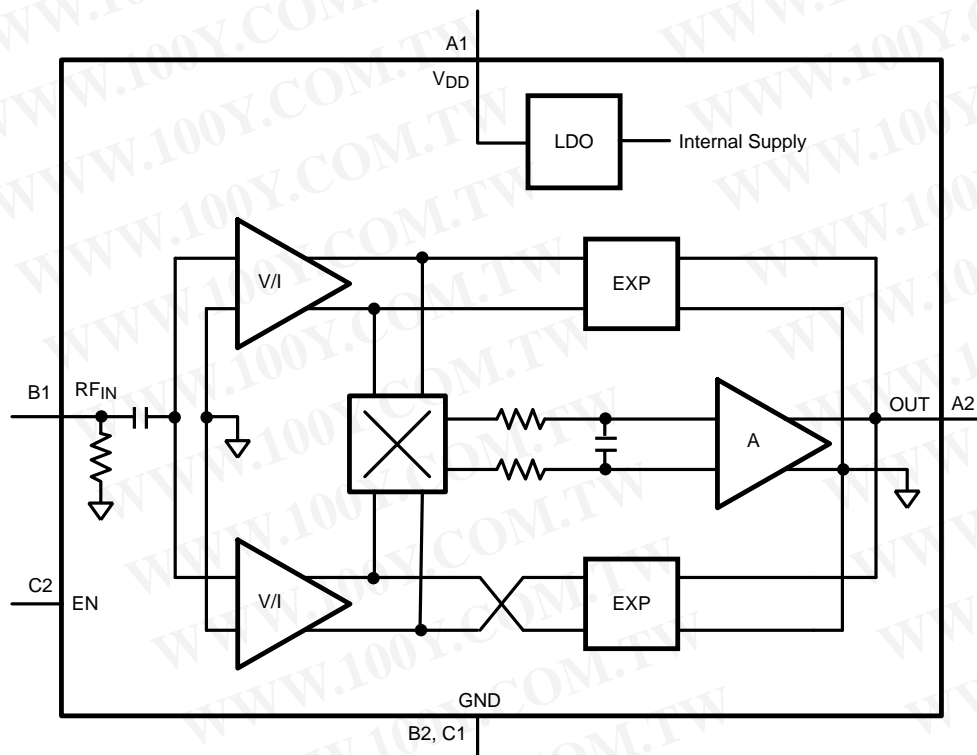


Figure 2. LMH2110

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### Typical Performance Characteristics

Unless otherwise specified:  $T_A = 25^\circ\text{C}$ ,  $V_{\text{BAT}} = 2.7\text{V}$ ,  $R_{\text{Fin}} = 1900\text{ MHz CW}$  (Continuous Wave, unmodulated). Specified errors are input referred.

Supply Current vs. Supply Voltage (Active)

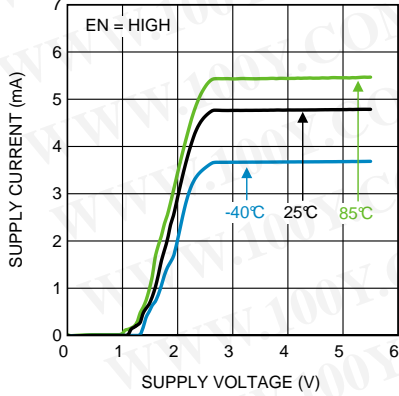


Figure 3.

Supply Current vs. Supply Voltage (Shutdown)

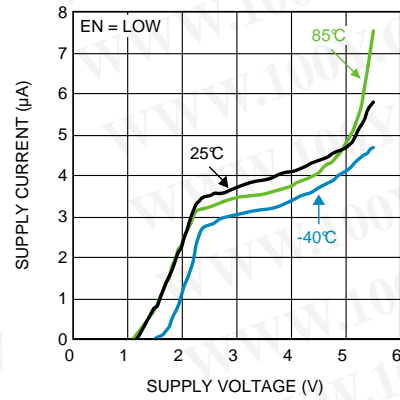


Figure 4.

Supply Current vs. Enable Voltage (EN)

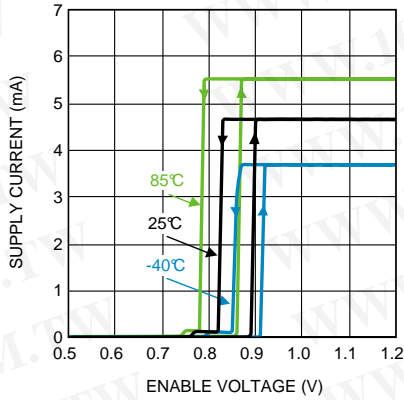


Figure 5.

Supply Current vs. RF Input Power

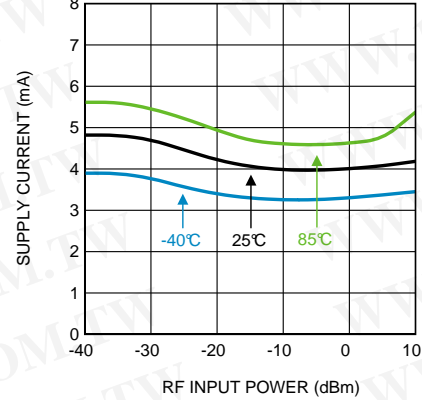


Figure 6.

Sourcing Output Current vs. RF Input Power

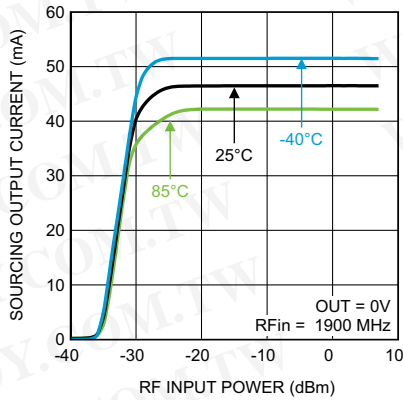


Figure 7.

Sinking Output Current vs. RF Input Power

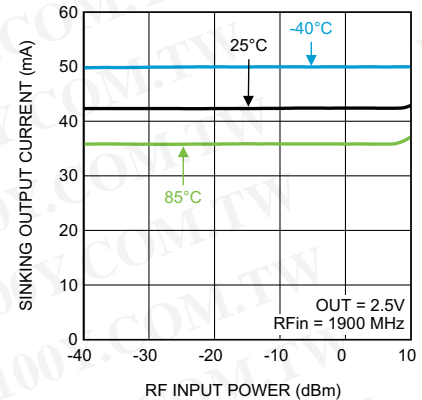


Figure 8.

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**Typical Performance Characteristics (continued)**

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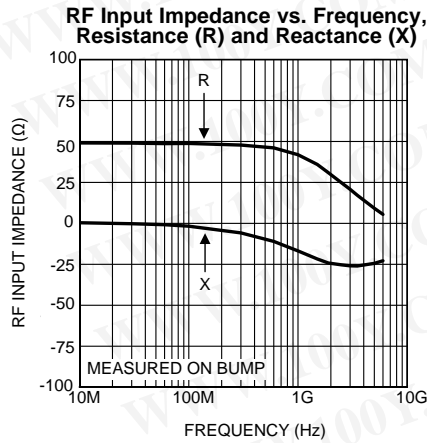


Figure 9.

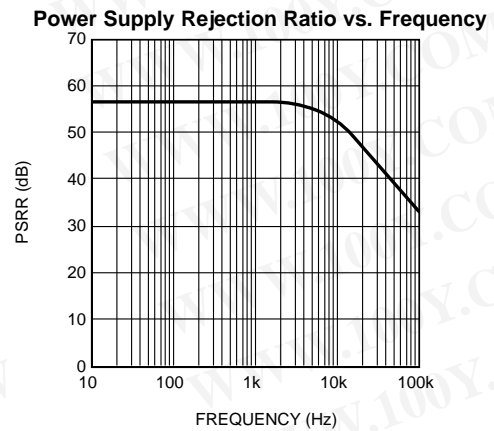


Figure 10.

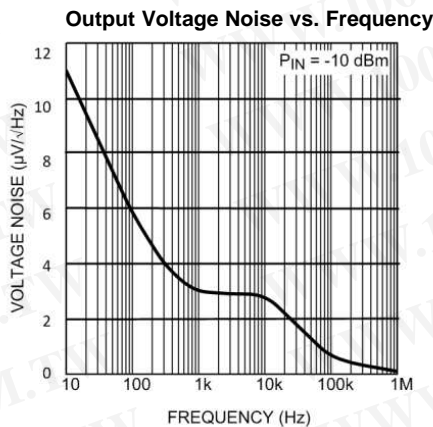


Figure 11.

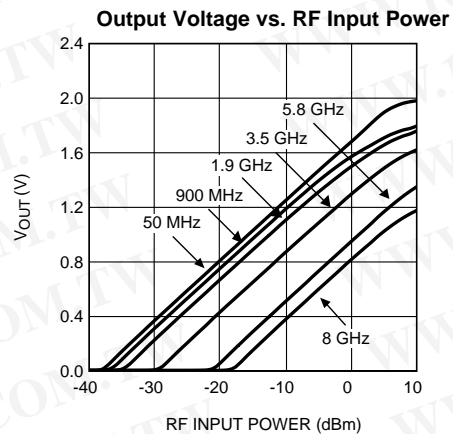


Figure 12.

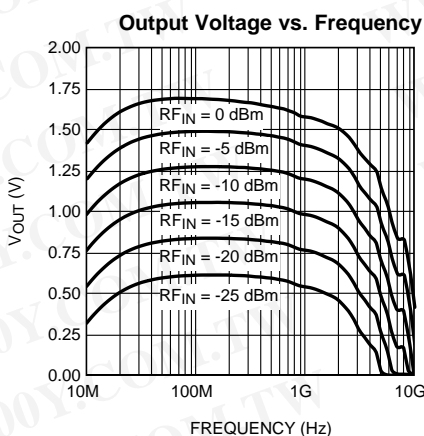


Figure 13.

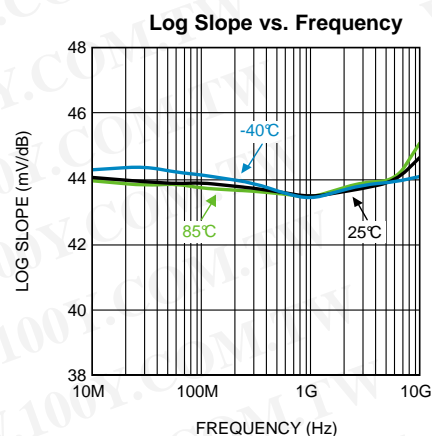


Figure 14.

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**Typical Performance Characteristics (continued)**

Unless otherwise specified:  $T_A = 25^\circ\text{C}$ ,  $V_{BAT} = 2.7\text{V}$ ,  $R_{Fin} = 1900\text{ MHz CW}$  (Continuous Wave, unmodulated). Specified errors are input referred.

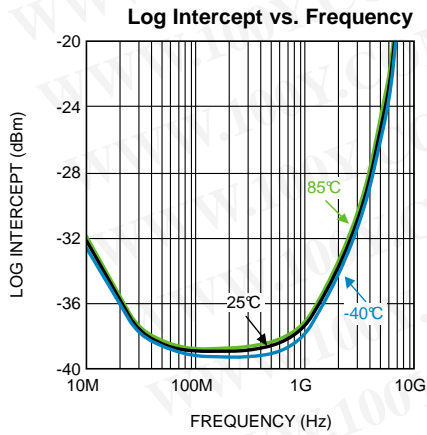


Figure 15.

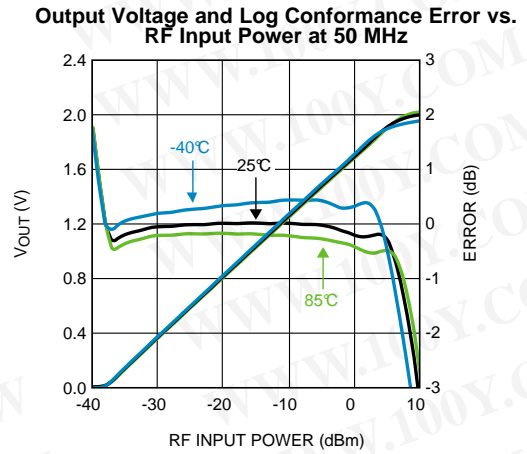


Figure 16.

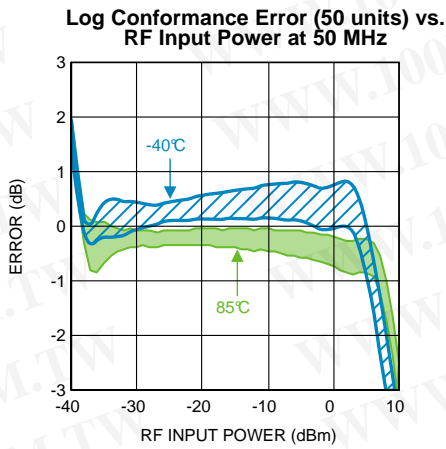


Figure 17.

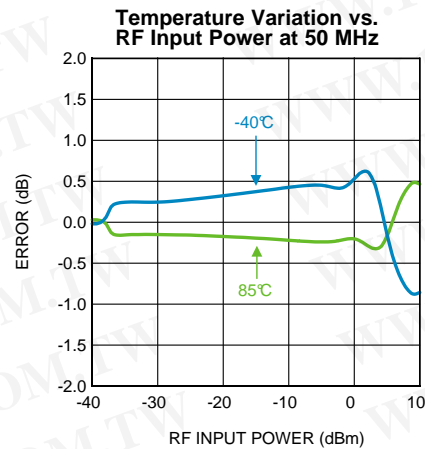


Figure 18.

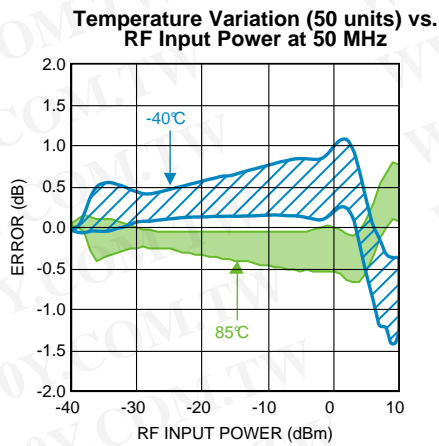


Figure 19.

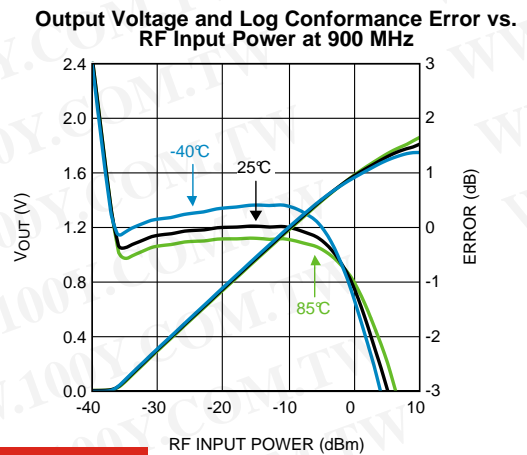


Figure 20.

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Typical Performance Characteristics (continued)

Unless otherwise specified:  $T_A = 25^\circ\text{C}$ ,  $V_{BAT} = 2.7\text{V}$ ,  $R_{Fin} = 1900\text{ MHz CW}$  (Continuous Wave, unmodulated). Specified errors are input referred.

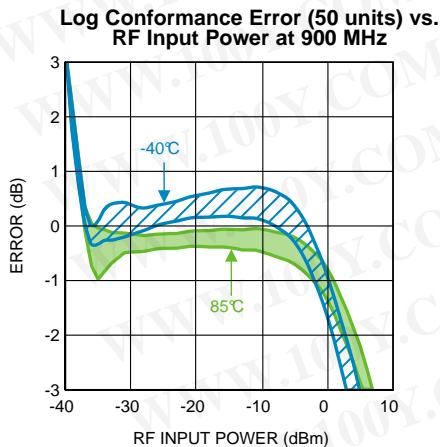


Figure 21.

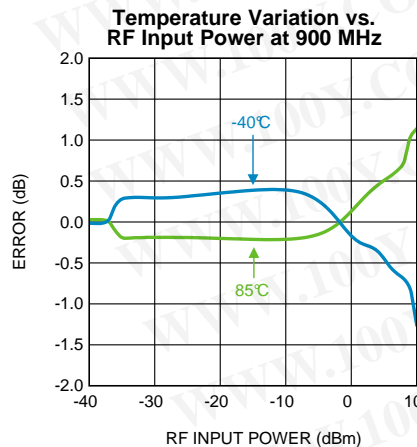


Figure 22.

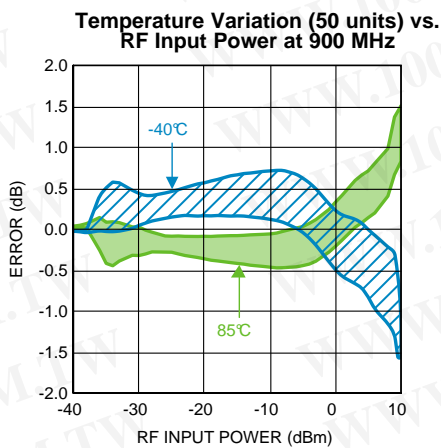


Figure 23.

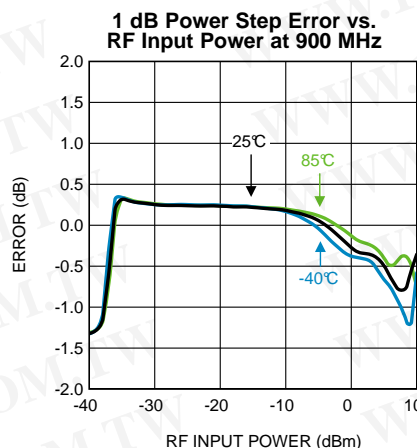


Figure 24.

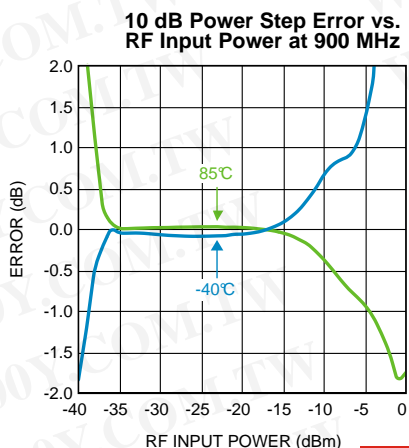


Figure 25.

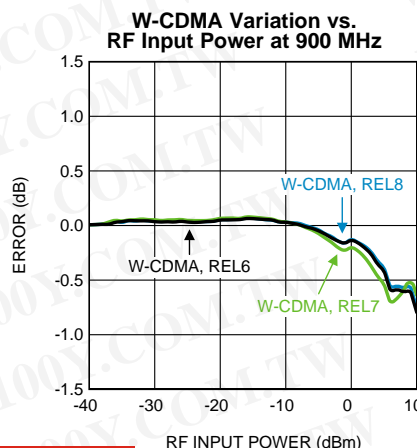


Figure 26.

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**Typical Performance Characteristics (continued)**

Unless otherwise specified:  $T_A = 25^\circ\text{C}$ ,  $V_{BAT} = 2.7\text{V}$ ,  $R_{Fin} = 1900\text{ MHz CW}$  (Continuous Wave, unmodulated). Specified errors are input referred.

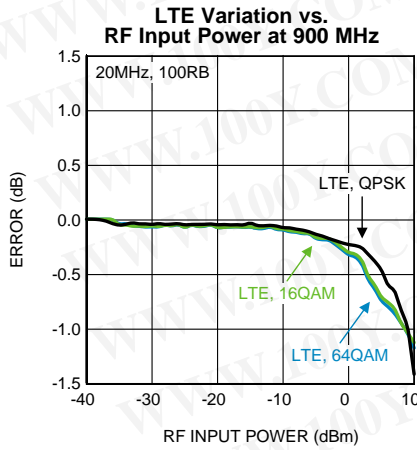


Figure 27.

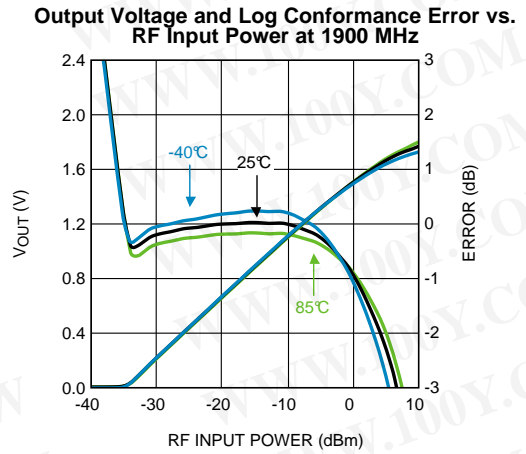


Figure 28.

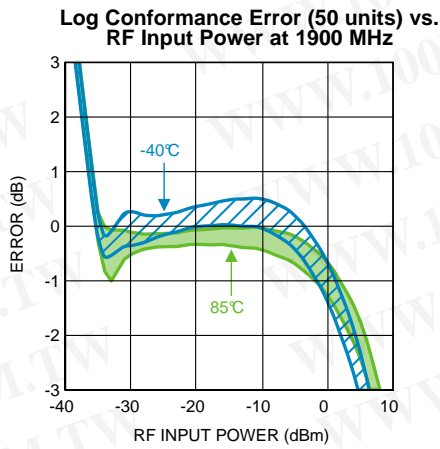


Figure 29.

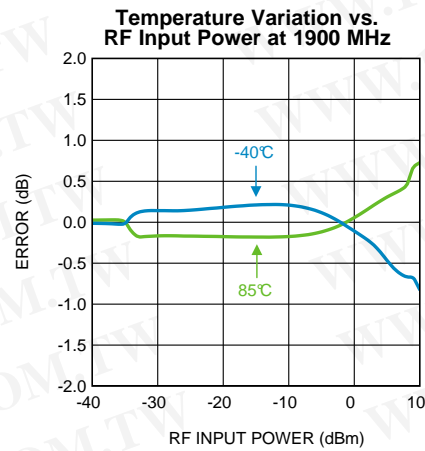


Figure 30.

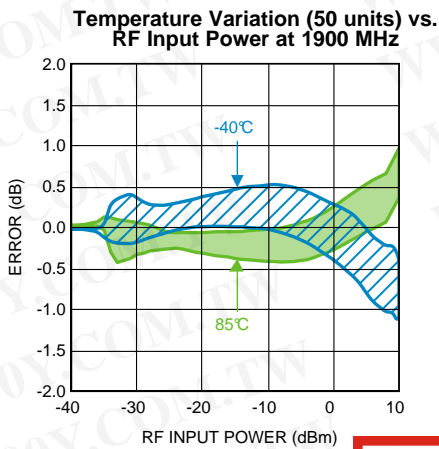


Figure 31.

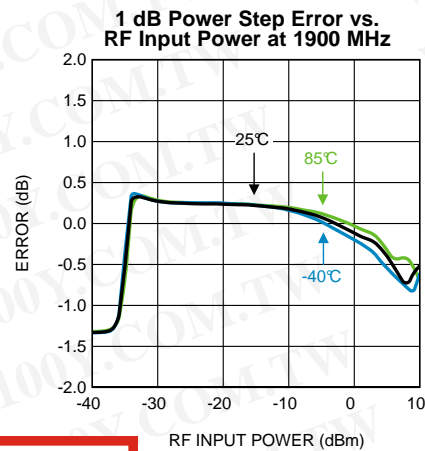


Figure 32.

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Typical Performance Characteristics (continued)

Unless otherwise specified:  $T_A = 25^\circ\text{C}$ ,  $V_{BAT} = 2.7\text{V}$ ,  $R_{Fin} = 1900\text{ MHz CW}$  (Continuous Wave, unmodulated). Specified errors are input referred.

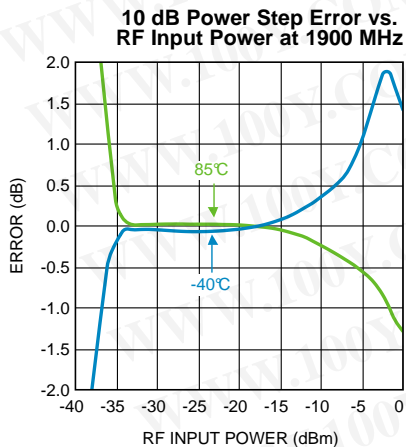


Figure 33.

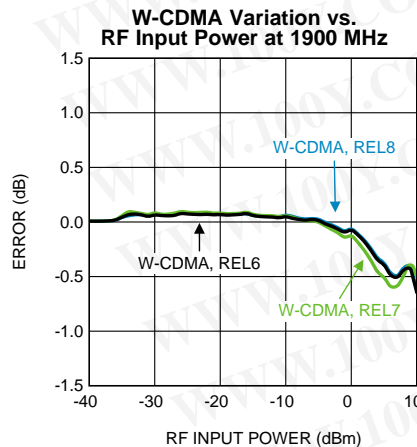


Figure 34.

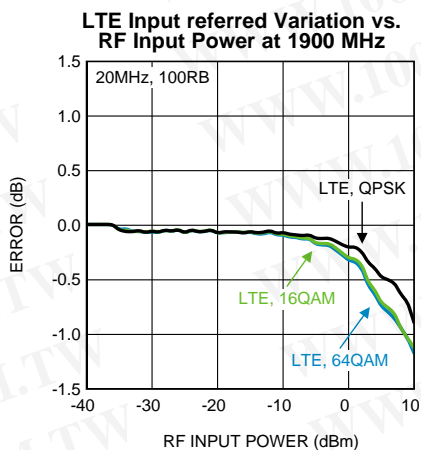


Figure 35.

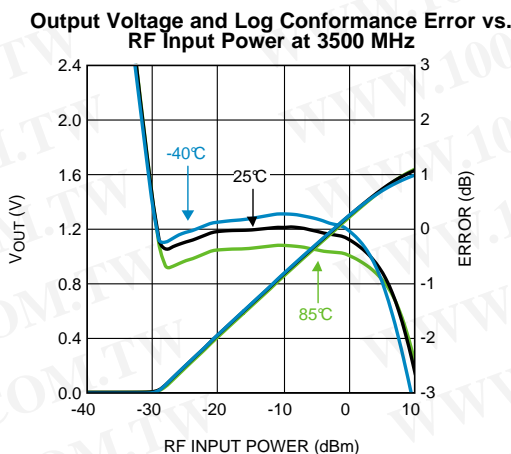


Figure 36.

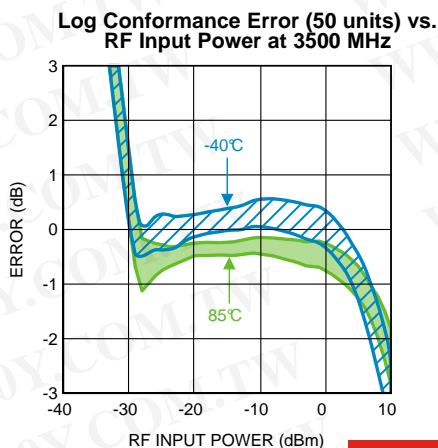


Figure 37.

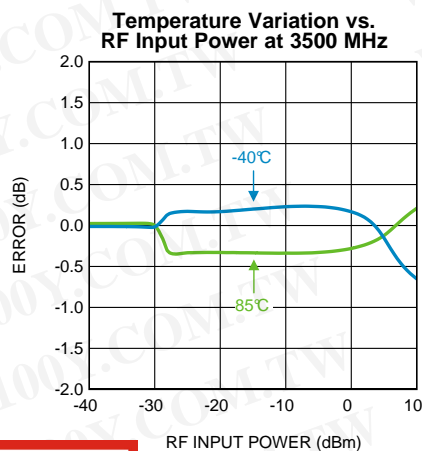


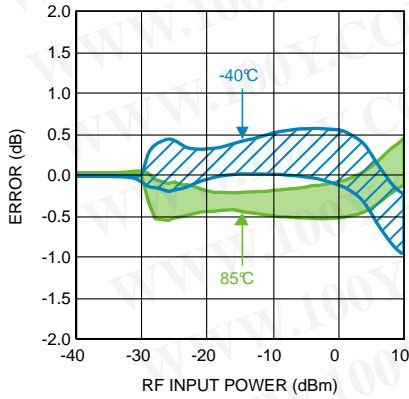
Figure 38.

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**Typical Performance Characteristics (continued)**

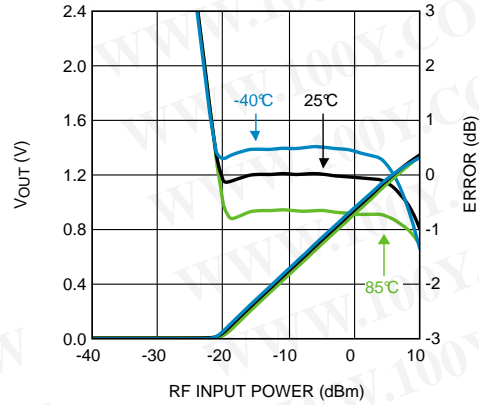
Unless otherwise specified:  $T_A = 25^\circ\text{C}$ ,  $V_{BAT} = 2.7\text{V}$ ,  $R_{Fin} = 1900\text{ MHz CW}$  (Continuous Wave, unmodulated). Specified errors are input referred.

**Temperature Variation (50 units) vs. RF Input Power at 3500 MHz**



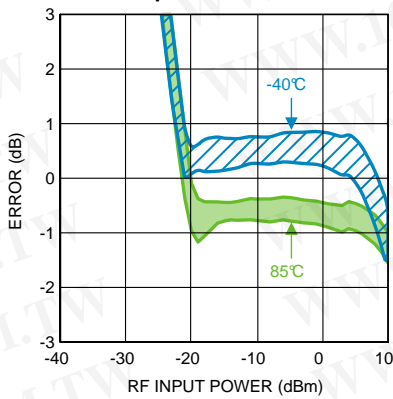
**Figure 39.**

**Output Voltage and Log Conformance Error vs. RF Input Power at 5800 MHz**



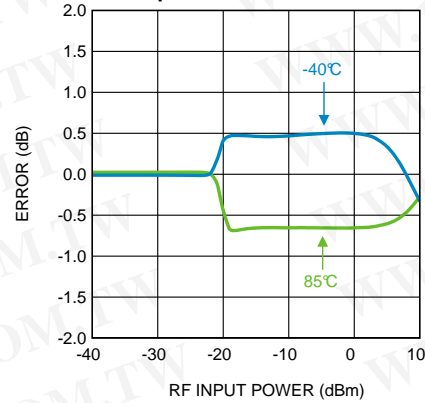
**Figure 40.**

**Log Conformance Error (50 units) vs. RF Input Power at 5800 MHz**



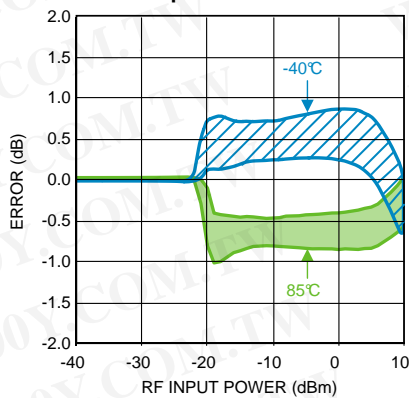
**Figure 41.**

**Temperature Variation vs. RF Input Power at 5800 MHz**



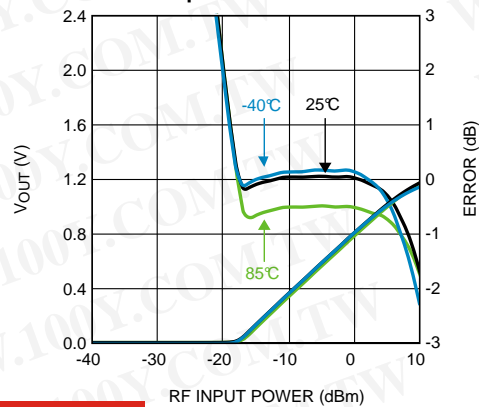
**Figure 42.**

**Temperature Variation (50 units) vs. RF Input Power at 5800 MHz**



**Figure 43.**

**Output Voltage and Log Conformance Error vs. RF Input Power at 8000 MHz**



**Figure 44.**

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**Typical Performance Characteristics (continued)**

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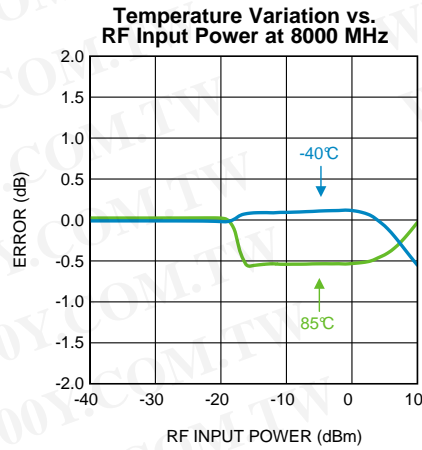


Figure 45.

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## APPLICATION INFORMATION

The LMH2110 is a 45 dB Logarithmic RMS power detector particularly suited for accurate power measurements of modulated RF signals that exhibit large peak-to-average ratios (PAR's). The RMS detector implements the exact definition of power resulting in a power measurement insensitive to high PAR's. Such signals are encountered e.g. in LTE and W-CDMA applications. The LMH2110 has an RF frequency range from 50 MHz to 8 GHz. It provides an output voltage that relates linearly to the RF input power in dBm. Its output voltage is highly insensitive to temperature and supply variations.

### Typical Application

The LMH2110 can be used in a wide variety of applications like LTE, W-CDMA, CDMA, GSM. This section discusses the LMH2110 in a typical transmit power control loop for such applications.

Transmit-power-control-loop circuits make the transmit power level insensitive to power amplifier (PA) inaccuracy. This is desired, since power amplifiers are non-linear devices and temperature dependent, making it hard to estimate the exact transmit power level. If a control loop is used, the inaccuracy of the PA is eliminated from the overall accuracy of the transmit power level. The accuracy of the transmit power level now depends on the RF detector accuracy instead. The LMH2110 is especially suited for transmit power control applications, since it accurately measures transmit power and is insensitive to temperature, supply voltage and modulation variations.

Figure 46 shows a simplified schematic of a typical transmit power control system. The output power of the PA is measured by the LMH2110 through a directional coupler. The measured output voltage of the LMH2110 is digitized by the ADC inside the baseband chip. Accordingly, the baseband controls the PA output power level by changing the gain control signal of the RF VGA. Although the output ripple of the LMH2110 is typically low enough, an optional low-pass filter can be placed in between the LMH2110 and the ADC to further reduce the ripple.

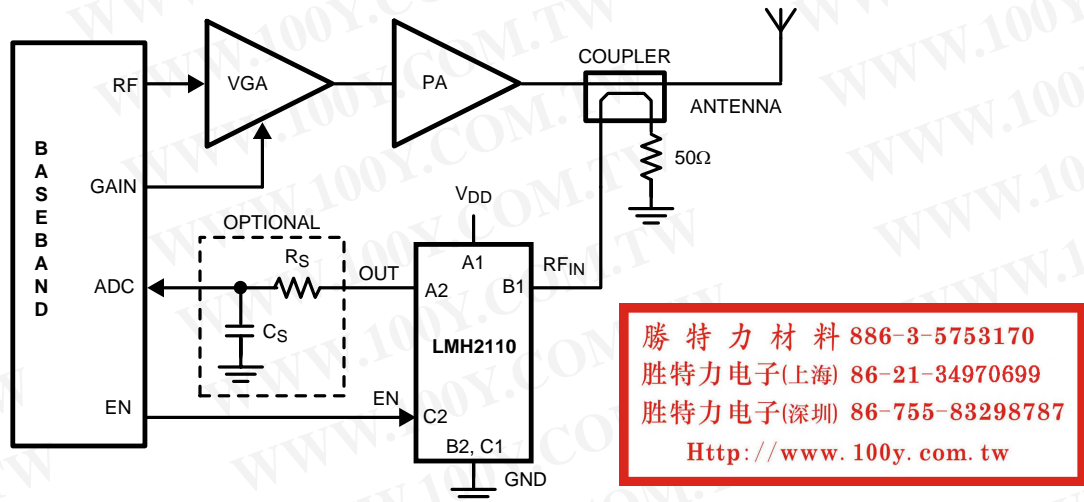


Figure 46. Transmit Power Control System

### Accurate Power Measurement

Detectors have evolved over the years along with the communication standards. Newer communication standards like LTE and W-CDMA raise the need for more advanced accurate power detectors. To be able to distinguish the various detector types it is important to understand what the ideal power measurement should look like and how a power measurement is implemented.

Power is a metric for the average energy content of a signal. By definition it is not a function of the signal shape over time. In other words, the power content of a 0 dBm sine wave is identical to the power content of a 0 dBm square wave or a 0 dBm W-CDMA signal; all these signals have the same average power content.

The average power can be described by the following formula:



$$P = \frac{1}{T} \int_0^T \frac{v(t)^2}{R} dt = \frac{V_{RMS}^2}{R}$$

where

- T is the time interval over which is averaged
- v(t) is the instantaneous voltage at time t
- R is the resistance in which the power is dissipated
- $V_{RMS}$  is the equivalent RMS voltage

(1)

According to aforementioned formula for power, an exact power measurement can be done via measuring the RMS voltage ( $V_{RMS}$ ) of a signal. The RMS voltage is described by:

$$V_{RMS} = \sqrt{\frac{1}{T} \int v(t)^2 dt}$$

(2)

Implementing the exact formula for RMS can be difficult though. A simplification can be made in determining the average power when information about the waveform is available. If the signal shape is known, the relationship between RMS value and, for instance, the peak value of the RF signal is also known. It thus enables a measurement based on measuring peak voltage rather than measuring the RMS voltage. To calculate the RMS value (and therewith the average power), the measured peak voltage is translated into an RMS voltage based on the waveform characteristics. A few examples:

- Sine wave:  $V_{RMS} = V_{PEAK} / \sqrt{2}$
- Square wave:  $V_{RMS} = V_{PEAK}$
- Saw-tooth wave:  $V_{RMS} = V_{PEAK} / \sqrt{3}$

For more complex waveforms it is not always easy to determine the exact relationship between RMS value and peak value. A peak measurement can then become impractical. An approximation can be used for the  $V_{RMS}$  to  $V_{PEAK}$  relationship but it can result in a less accurate average power estimate.

Depending on the detection mechanism, power detectors may produce a slightly different output signal in response to the earlier mentioned waveforms, even though the average power level of these signals are the same. This error is due to the fact that not all power detectors strictly implement the definition for signal power, being the root mean square (RMS) of the signal. To cover for the systematic error in the output response of a detector, calibration can be used. After calibration a look-up table corrects for the error. Multiple look-up tables can be created for different modulation schemes.

## Types of RF Detectors

This section provides an overview of detectors based on their detection principle. Detectors that will be discussed are:

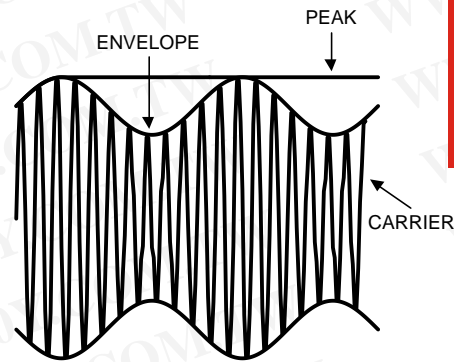
- [Peak Detectors](#)
- [LOG Amp Detectors](#)
- [RMS Detectors](#)

### Peak Detectors

A peak detector is one of the simplest types of detectors. According to the naming, the peak detector “stores” the highest value arising in a certain time window. However, usually a peak detector is used with a relative long holding time when compared to the carrier frequency and a relative short holding time with respect to the envelope frequency. In this way a peak detector is used as AM demodulator or envelope tracker ([Figure 47](#)).

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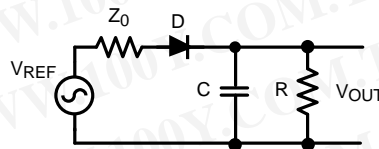
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**Figure 47. Peak detection vs. envelope tracking**

A peak detector usually has a linear response. An example of this is a diode detector (Figure 48). The diode rectifies the RF input voltage and subsequently the RC filter determines the averaging (holding) time. The selection of the holding time configures the diode detector for its particular application. For envelope tracking a relatively small RC time constant is chosen, such that the output voltage tracks the envelope nicely. A configuration with a relatively large time constant can be used for supply regulation of the power amplifier (PA). Controlling the supply voltage of the PA can reduce power consumption significantly. The optimal mode of operation is to set the supply voltage such that it is just above the maximum output voltage of the PA. A diode detector with relative large RC time constant measures this maximum (peak) voltage.



**Figure 48. Diode Detector**

Since peak detectors measure a peak voltage, their response is inherently depended on the signal shape or modulation form as discussed in the previous section. Knowledge about the signal shape is required to determine an RMS value. For complex systems having various modulation schemes, the amount of calibration and look-up tables can become unmanageable.

### LOG Amp Detectors

LOG Amp detectors are widely used RF power detectors for GSM and the early W-CDMA systems. The transfer function of a LOG amp detector has a linear-in-dB response, which means that the output in volts changes linearly with the RF power in dBm. This is convenient since most communication standards specify transmit power levels in dBm as well. LOG amp detectors implement the logarithmic function by a piecewise linear approximation. Consequently, the LOG amp detector does not implement an exact power measurement, which implies a dependency on the signal shape. In systems using various modulation schemes calibration and lookup tables might be required.

### RMS Detectors

An RMS detector has a response that is insensitive to the signal shape and modulation form. This is because its operation is based on exact determination of the average power, i.e. it implements:

$$V_{\text{RMS}} = \sqrt{\frac{1}{T} \int v(t)^2 dt}$$

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(3)

RMS detectors are in particular suited for the newer communication standards like W-CDMA and LTE that exhibit large peak-to-average ratios and different modulation schemes (signal shapes). This is a key advantage compared to other types of detectors in applications that employ signals with high peak-to-average power variations or different modulation schemes. For example, the RMS detector response to a 0 dBm modulated W-CDMA signal and a 0 dBm unmodulated carrier is essentially equal. This eliminates the need for long calibration procedures and large calibration tables in the baseband due to different applied modulation schemes.

### LMH2110 RF Power Detector

For optimal performance of the LMH2110, it needs to be configured correctly in the application. The detector will be discussed by means of its block diagram (Figure 49). Subsequently, the details of the electrical interfacing are separately discussed for each pin.

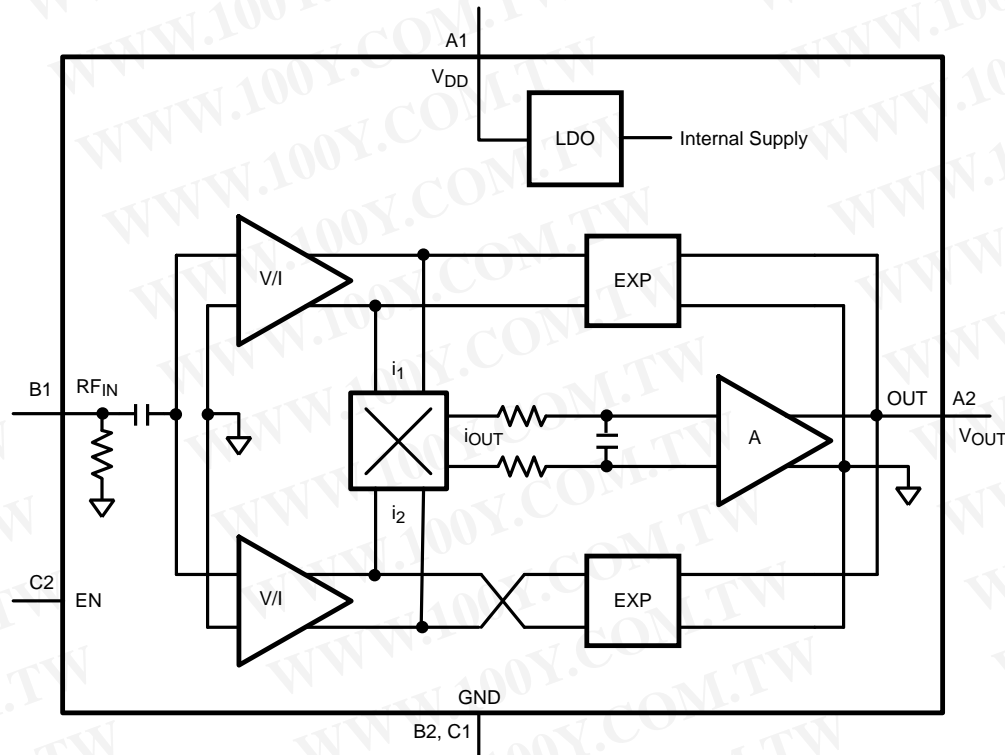


Figure 49. Block Diagram

For measuring the RMS (power) level of a signal, the time average of the squared signal needs to be measured as described in section [Accurate Power Measurement](#). This is implemented in the LMH2110 by means of a multiplier and a low-pass filter in a negative-feedback loop. A simplified block diagram of the LMH2110 is depicted in Figure 49. The core of the loop is a multiplier. The two inputs of the multiplier are fed by ( $i_1$ ,  $i_2$ ):

$$i_1 = i_{LF} + i_{RF} \quad (4)$$

$$i_2 = i_{LF} - i_{RF} \quad (5)$$

in which  $i_{LF}$  is a current depending on the DC output voltage of the RF detector and  $i_{RF}$  is a current depending on the RF input signal. The output of the multiplier ( $i_{OUT}$ ) is the product of these two current and equals:

$$i_{out} = \frac{i_{LF}^2 - i_{RF}^2}{I_0} \quad (6)$$

in which  $I_0$  is a normalizing current. By a low-pass filter at the output of the multiplier the DC term of this current is isolated and integrated. The input of the amplifier A acts as the nulling point of the negative feedback loop, yielding:

$$\int i_{LF}^2 dt = \int i_{RF}^2 dt \quad (7)$$

which implies that the average power content of the current related to the output voltage of the LMH2110 is made equal to the average power content of the current related to the RF input signal.

For a negative-feedback system, the transfer function is given by the inverse function of the feedback block. Therefore, to have a logarithmic transfer for this RF detector, the feedback network implements an exponential function resulting in an overall transfer function for the LMH2110 of:

$$V_{out} = V_0 \log \left( \frac{1}{V_x} \sqrt{\int V_{RF}^2 dt} \right) \quad (8)$$

in which  $V_0$  and  $V_x$  are normalizing voltages. Note that as a result of the feedback loop also a square-root is implemented yielding the RMS function.

Given this architecture for the RF detector, the high-performance of the LMH2110 can be understood. In theory the accuracy of the logarithmic transfer is set by:

- The exponential feedback network, which basically needs to process a DC signal only.
- A high loop gain for the feedback loop, which is specified by the amplifier gain  $A$ .

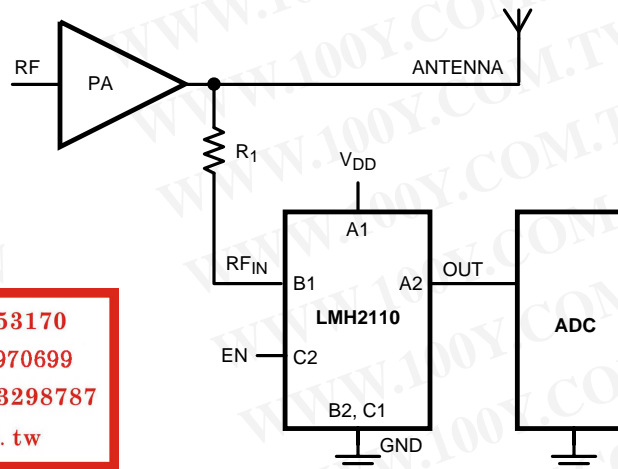
The RMS functionality is inherent to the feedback loop and the use of a multiplier. So, a very accurate LOG-RMS RF power detector is obtained.

To ensure a low dependency on the supply voltage, the internal detector circuitry is supplied via a low drop-out (LDO) regulator. This enables the usage of a wide range of supply voltage (2.7V to 5V) in combination with a low sensitivity of the output signal for the external supply voltage.

### RF Input

RF systems typically use a characteristic impedance of  $50\Omega$ . The LMH2110 is no exception to this. The RF input pin of the LMH2110 has an input impedance of  $50\Omega$ . It enables an easy, direct connection to a directional coupler without the need for additional components (Figure 46). For an accurate power measurement the input power range of the LMH2110 needs to be aligned with the output power range of the power amplifier. This can be done by selecting a directional coupler with the correct coupling factor.

Since the LMH2110 has a constant input impedance, a resistive divider can also be used in stead of a directional coupler (Figure 50).



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**Figure 50. Application with Resistive Divider**

Resistor  $R_1$  implements an attenuator together with the detector input impedance to match the output range of the PA to the input range of the LMH2110. The attenuation ( $A_{dB}$ ) realized by  $R_1$  and the effective input impedance of the LMH2110 equals:

$$A_{dB} = 20 \text{LOG} \left[ 1 + \frac{R_1}{R_{IN}} \right] \quad (9)$$

Solving this expression for  $R_1$  yields:

$$R_1 = \left[ 10^{\frac{A_{dB}}{20}} - 1 \right] R_{IN} \quad (10)$$

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Suppose the desired attenuation is 30 dB with a given LMH2110 input impedance of 50Ω, the resistor  $R_1$  needs to be 1531Ω. A practical value is 1.5 kΩ. Although this is a cheaper solution than the application with directional coupler, it also comes with a disadvantage. After calculating the resistor value it is possible that the realized attenuation is less than expected. This is because of the parasitic capacitance of resistor  $R_1$  which results in a lower actual realized attenuation. Whether the attenuation will be reduced depends on the frequency of the RF signal and the parasitic capacitance of resistor  $R_1$ . Since the parasitic capacitance varies from resistor to resistor, exact determination of the realized attenuation can be difficult. A way to reduce the parasitic capacitance of resistor  $R_1$  is to realize it as a series connection of several separate resistors.

### Enable

To save power, the LMH2110 can be brought into a low-power shutdown mode by means of the enable pin (EN). The device is active for EN = HIGH ( $V_{EN} > 1.1V$ ) and in the low-power shutdown mode for EN = LOW ( $V_{EN} < 0.6V$ ). In this state the output of the LMH2110 is switched to a high impedance mode. This high impedance mode prevents the discharge of the optional low-pass filter which is good for the power efficiency. Using the shutdown function, care must be taken not to exceed the absolute maximum ratings. Since the device has an internal operating voltage of 2.5V, the voltage level on the enable should not be higher than 3V to prevent damage to the device. Also enable voltage levels lower than 400 mV below GND should be prevented. In both cases the ESD devices start to conduct when the enable voltage range is exceeded and excessive current will be drawn. A correct operation is not ensured then. The absolute maximum ratings are also exceeded when the enable (EN) is switched to HIGH (from shutdown to active mode) while the supply voltage is switched off. This situation should be prevented at all times. A possible solution to protect the device is to add a resistor of 1 kΩ in series with the enable input to limit the current.

### Output

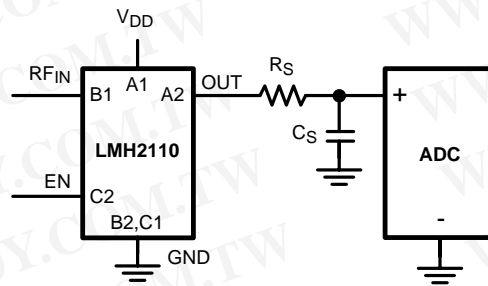
The output of the LMH2110 provides a DC voltage that is a measure for the applied RF power to the input pin. The output voltage has a linear-in-dB response for an applied RF signal.

RF power detectors can have some residual ripple on the output due to the modulation of the applied RF signal. The residual ripple on the LMH2110's output is small though and therefore additional filtering is usually not needed. This is because its internal averaging mechanism reduces the ripple significantly. For some modulation types however, having very high peak-to-average ratios, additional filtering might be useful.

Filtering can be applied by an external low-pass filter. It should be realized that filtering reduces not only the ripple, but also increases the response time. In other words, it takes longer before the output reaches its final value. A trade-off should be made between allowed ripple and allowed response time. The filtering technique is depicted in [Figure 51](#). The filtering of the low pass output filter is realized by resistor  $R_S$  and capacitor  $C_S$ . The -3 dB bandwidth of this filter can be calculated by:

$$f_{-3 \text{ dB}} = 1 / (2\pi R_S C_S) \quad (11)$$

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**Figure 51. Low-Pass Output Filter for Residual Ripple Reduction**

The output impedance of the LMH2110 is HIGH in shutdown. This is especially beneficial in pulsed mode systems. It ensures a fast settling time when the device returns from shutdown into active mode and reduces power consumption.

In pulse mode systems, the device is active only during a fraction of the time. During the remaining time the device is in low-power shutdown. Pulsed mode system applications usually require that the output value is available at all times. This can be realized by a capacitor connected between the output and GND that “stores” the output voltage level. To apply this principle it should be ensured that discharging of the capacitor is minimized in shutdown mode. The connected ADC input should thus have a high input impedance to prevent a possible discharge path through the ADC. When an additional filter is applied at the output, the capacitor of the RC-filter can be used to store the output value. An LMH2110 with a high impedance shutdown mode save power in pulse mode systems. This is because the capacitor  $C_S$  doesn't need to be fully re-charged each cycle.

### Supply

The LMH2110 has an internal LDO to handle supply voltages between 2.7V to 5V. This enables a direct connection to the battery in cell phone applications. The high PSRR of the LMH2110 ensures that the performance is constant over its power supply range.

### Specifying Detector Performance

The performance of the LMH2110 can be expressed by a variety of parameters. This section discusses the key parameters.

#### Dynamic Range

The LMH2110 is designed to have a predictable and accurate response over a certain input power range. This is called the dynamic range (DR) of a detector. For determining the dynamic range a couple of different criteria can be used. The most commonly used ones are:

- Log conformance error,  $E_{LC}$
- Variation over temperature error,  $E_{VOT}$
- 1 dB step error,  $E_{1\text{ dB}}$
- 10 dB step error,  $E_{10\text{ dB}}$
- Variation due to modulation,  $E_{MOD}$

The specified dynamic range is the range in which the specified error metric is within a predefined window. An explanation of these errors is given in the following paragraphs.

#### Log Conformance error

The LMH2110 implements a logarithmic function. In order to describe how close the transfer is to an ideal logarithmic function the log conformance error is used. To calculate the log conformance error the detector transfer function is modeled as a linear-in-dB relationship between the input power and the output voltage.

The ideal linear-in-dB transfer is modeled by 2 parameters:

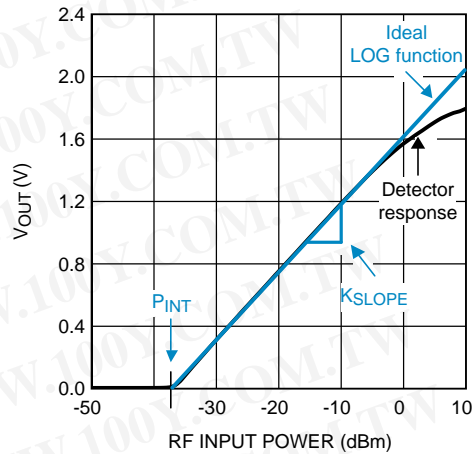
- Slope
- Intercept

and is described by:

$$V_{OUT} = K_{SLOPE} (P_{IN} - P_{INT})$$

where

- $K_{SLOPE}$  is the slope of the line in mV/dB
- $P_{IN}$  the input power level
- $P_{INT}$  is the power level in dBm at which the line intercepts  $V_{OUT} = 0V$  (See Figure 52). (12)



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Figure 52. Ideal Logarithmic Response

To determine the log conformance error two steps are required:

1. Determine the best fitted line at 25°C.
2. Determine the difference between the actual data and the best fitted line.

The best fit can be determined by standard routines. A careful selection of the fit range is important. The fit range should be within the normal range of operation of the device. Outcome of the fit is  $K_{SLOPE}$  and  $P_{INT}$ .

Subsequently, the difference between the actual data and the best fitted line is determined. The log conformance is specified as an input referred error. The output referred error is therefore divided by the  $K_{SLOPE}$  to obtain the input referred error. The log conformance error is calculated by the following equation:

$$E_{LC} = \frac{V_{OUT} - K_{SLOPE\ 25^{\circ}C} (P_{IN} - P_{INT\ 25^{\circ}C})}{K_{SLOPE\ 25^{\circ}C}}$$

where

- $V_{OUT}$  is the measured output voltage at a power level at  $P_{IN}$  at a temperature.  $K_{SLOPE\ 25^{\circ}C}$  (mV/dB)
- $P_{INT\ 25^{\circ}C}$  (dBm) are the parameters of the best fitted line of the 25°C transfer (13)

In Figure 53 it can be seen that both the error with respect to the ideal LOG response as well as the error due to temperature variation are included in this error metric. This is because the measured data for all temperatures is compared to the fitted line at 25°C. The measurement result of a typical LMH2110 in Figure 53 shows a dynamic range of 36 dB for  $E_{LC} = \pm 1dB$ .

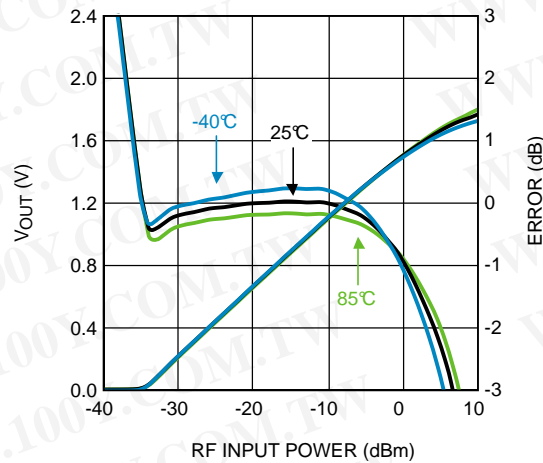


Figure 53.  $V_{OUT}$  and  $E_{LC}$  vs. RF input Power at 1900 MHz

**Variation over Temperature Error**

In contrast to the log conformance error, the variation over temperature error ( $E_{VOT}$ ) purely measures the error due to temperature variation. The measured output voltage at 25°C is subtracted from the output voltage at another temperature. Subsequently, it is translated into an input referred error by dividing it by  $K_{SLOPE}$  at 25°C. The equation for variation over temperature is given by:

$$E_{VOT} = (V_{OUT\_TEMP} - V_{OUT\ 25^\circ C}) / K_{SLOPE\ 25^\circ C} \tag{14}$$

The variation over temperature is shown in Figure 54, where a dynamic range of 41 dB is obtained (from  $P_{MIN} = -36$  dBm) for  $E_{VOT} = \pm 0.5$  dB.

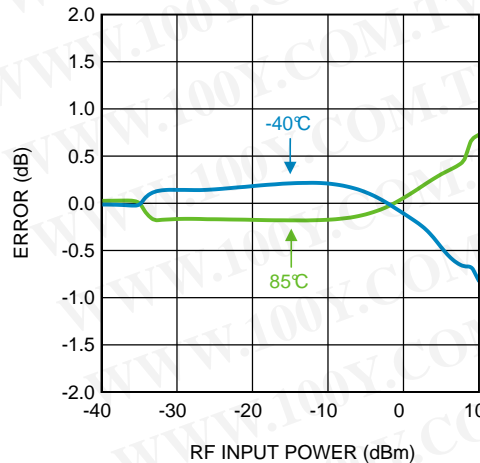


Figure 54.  $E_{VOT}$  vs. RF Input Power at 1900 MHz

**1 dB step error**

This parameter is a measure for the error for an 1 dB power step. According to a 3GPP specification, the error should be less than  $\pm 0.3$  dB. Often, this condition is used to define a useful dynamic range of the detector.

The 1 dB step error is calculated in 3 steps:

1. Determine the maximum sensitivity.
2. Determine average sensitivity.
3. Calculate the 1 dB step error.

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First the maximum sensitivity ( $S_{MAX}$ ) is calculated per temperature by determining the maximum difference between two output voltages for a 1 dB step within the power range:

$$S_{MAX} = V_{OUT P+1} - V_{OUT P} \quad (15)$$

For calculating the 1 dB step error an average sensitivity ( $S_{AVG}$ ) is used which is the average of the maximum sensitivity and an allowed minimum sensitivity ( $S_{MIN}$ ). The allowed minimum sensitivity is determined by the application. In this datasheet  $S_{MIN} = 30 \text{ mV/dB}$  is used. Subsequently, the average sensitivity can be calculated by:

$$S_{AVG} = (S_{MAX} + S_{MIN}) / 2 \quad (16)$$

The 1dB error is then calculated by:

$$E_{1 \text{ dB}} = (S_{ACTUAL} - S_{AVG}) / S_{AVG}$$

where

- $S_{ACTUAL}$  (actual sensitivity) is the difference between two output voltages for a 1 dB step at a given power level (17)

Figure 55 shows the typical 1 dB step error at 1900 MHz, where a dynamic range of 38 dB over temperature is obtained for  $E_{1dB} = \pm 0.3 \text{ dB}$ .

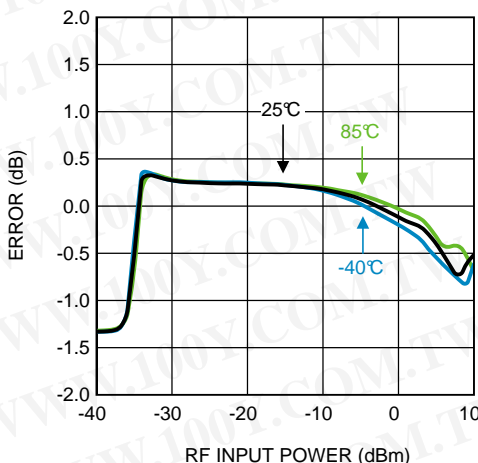


Figure 55. 1 dB Step Error vs. RF Input Power at 1900 MHz

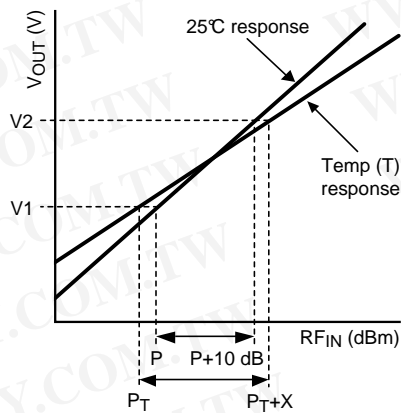
### 10 dB step error

This error is defined in a different manner than the 1 dB step error. This parameter shows the input power error over temperature when a 10 dB power step is made. The 10 dB step at 25°C is taken as a reference.

To determine the 10 dB step error first the output voltage levels ( $V_1$  and  $V_2$ ) for power levels “P” and “P+10dB” at the 25°C are determined (Figure 56). Subsequently these 2 output voltages are used to determine the corresponding power levels at temperature T ( $P_T$  and  $P_T+X$ ). The difference between those two power levels subtracted by 10 results in the 10 dB step error.

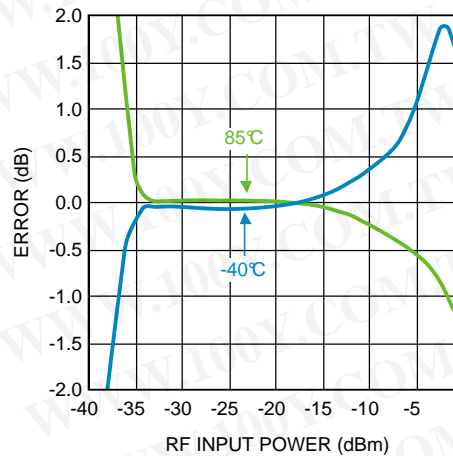
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**Figure 56. Graphical Representation of 10 dB Step calculations**

Figure 57 shows the typical 10 dB step error at 1900 MHz, where a dynamic range of 30 dB is obtained for  $E_{10dB} = \pm 1$  dB.



**Figure 57. 10 dB Step Error vs. RF Input Power at 1900 MHz**

### Variation due to Modulation

The response of an RF detector may vary due to different modulation schemes. How much it will vary depends on the modulation form and the type of detector. Modulation forms with high peak-to-average ratios (PAR) can cause significant variation, especially with traditional RF detectors. This is because the measurement is not an actual RMS measurement and is therefore waveform dependent.

To calculate the variation due to modulation ( $E_{MOD}$ ), the measurement result for an un-modulated RF carrier is subtracted from the measurement result of a modulated RF carrier. The calculations are similar to those for variation over temperature. The variation due to modulation can be calculated by:

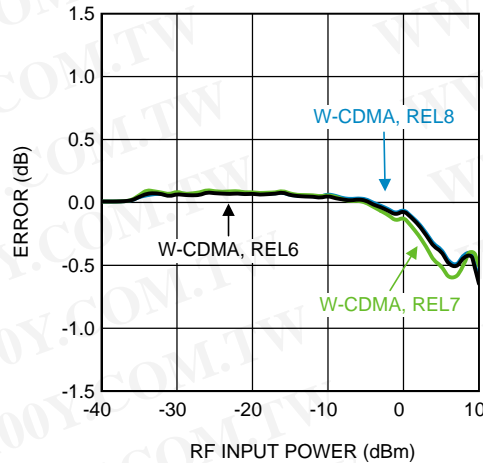
$$E_{MOD} = (V_{OUT\_MOD} - V_{OUT\_CW}) / K_{SLOPE}$$

where

- $V_{OUT\_MOD}$  is the measured output voltage for an applied power level of a modulated signal
- $V_{OUT\_CW}$  is the output voltage as a result of an applied un-modulated signal having the same power level (18)

Figure 58 shows the variation due to modulation for W-CDMA, where a  $E_{MOD}$  of 0.09 dB is obtained for a dynamic range from -38 dBm to -5 dBm.

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**Figure 58. Variation due to Modulation for W-CDMA**

### Layout Recommendations

As with any other RF device, careful attention must be paid to the board layout. If the board layout isn't properly designed, performance might be less than can be expected for the application.

The LMH2110 is designed to be used in RF applications, having a characteristic impedance of 50Ω. To achieve this impedance, the input of the LMH2110 needs to be connected via a 50Ω transmission line. Transmission lines can be created on PCBs using microstrip or (grounded) coplanar waveguide (GCPW) configurations.

In order to minimize injection of RF interference into the LMH2110 through the supply lines, the PCB traces for  $V_{DD}$  and GND should be minimized for RF signals. This can be done by placing a small decoupling capacitor between the  $V_{DD}$  and GND. It should be placed as close as possible to the  $V_{DD}$  and GND pins of the LMH2110.

### REVISION HISTORY

#### Changes from Revision B (March 2013) to Revision C

Page

- Changed layout of National Data Sheet to TI format ..... 27

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**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LMH2110TM/NOPB	ACTIVE	DSBGA	YFQ	6	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	P	Samples
LMH2110TMX/NOPB	ACTIVE	DSBGA	YFQ	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	P	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

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**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

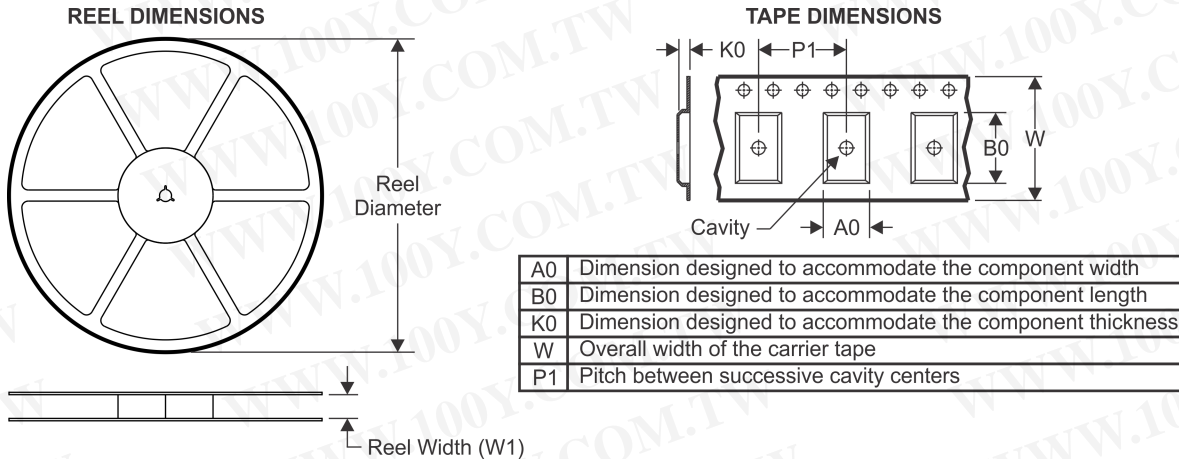
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

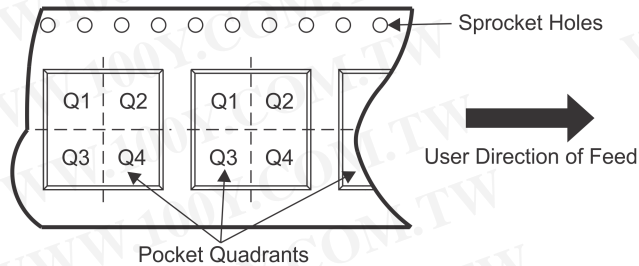
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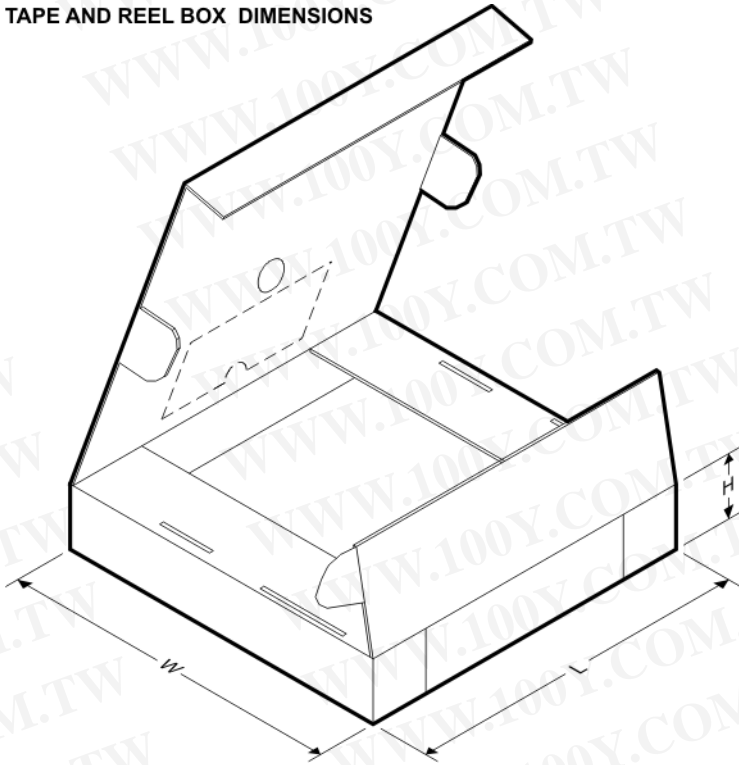
### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMH2110TM/NOPB	DSBGA	YFQ	6	250	178.0	8.4	0.89	1.3	0.7	4.0	8.0	Q1
LMH2110TMX/NOPB	DSBGA	YFQ	6	3000	178.0	8.4	0.89	1.3	0.7	4.0	8.0	Q1

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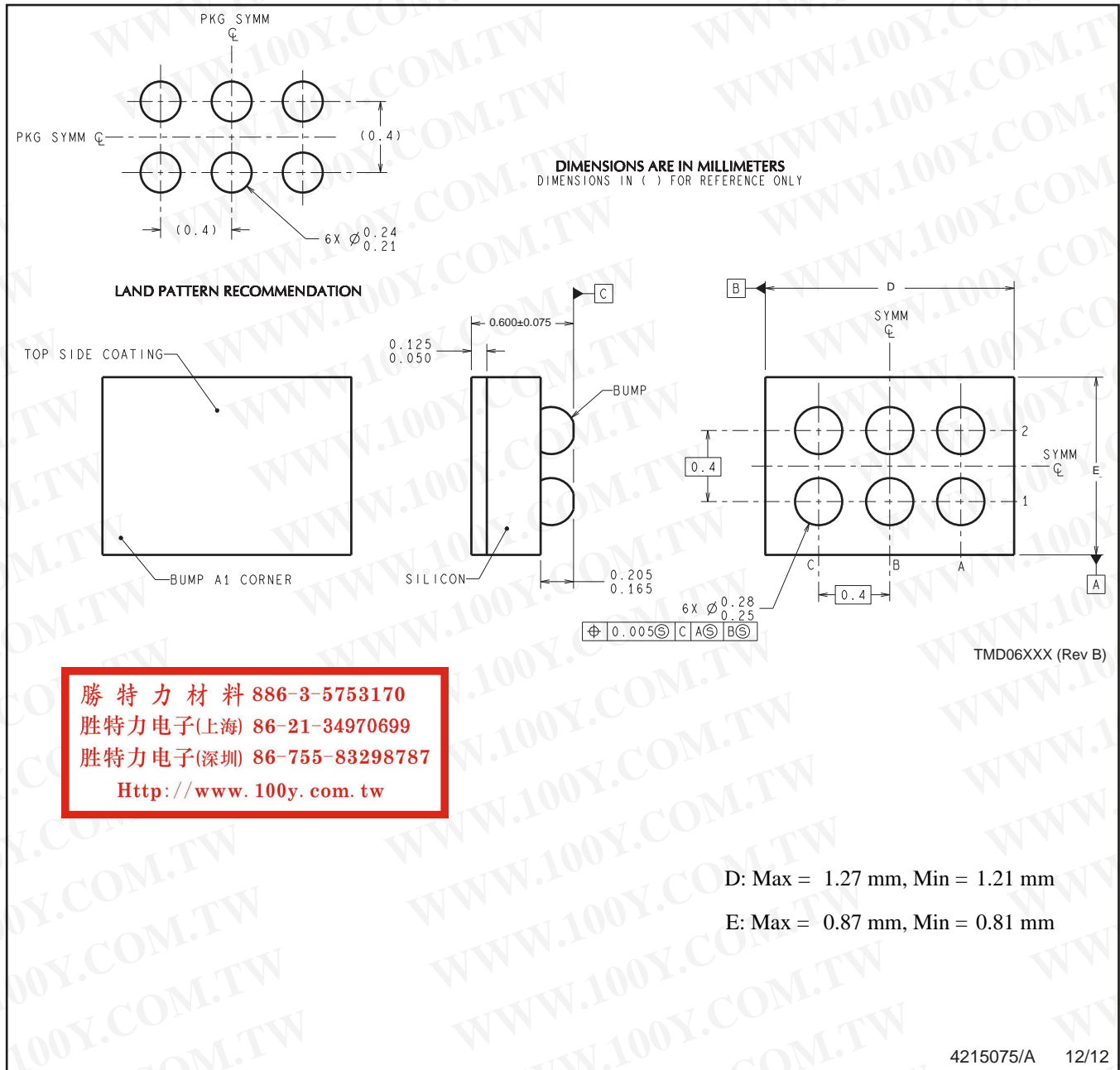
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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMH2110TM/NOPB	DSBGA	YFQ	6	250	210.0	185.0	35.0
LMH2110TMX/NOPB	DSBGA	YFQ	6	3000	210.0	185.0	35.0

YFQ0006



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.  
 B. This drawing is subject to change without notice.



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